

OKI Semiconductor

MSC23436A-xxBS12/DS12

4,194,304-Word × 36-Bit DRAM MODULE : FAST PAGE MODE TYPE

DESCRIPTION

The OKI MSC23436A-xxBS12/DS12 is a fully decoded 4,194,304-word × 36-bit CMOS Dynamic Random Access Memory Module composed of eight 16-Mb DRAMs (4M × 4) in SOJ packages and four 4-Mb DRAMs (4M × 1) in SOJ packages mounted with twelve decoupling capacitors on a 72-pin glass epoxy single-inline package. This module is generally used for memory expansion in parity applications such as workstations.

FEATURES

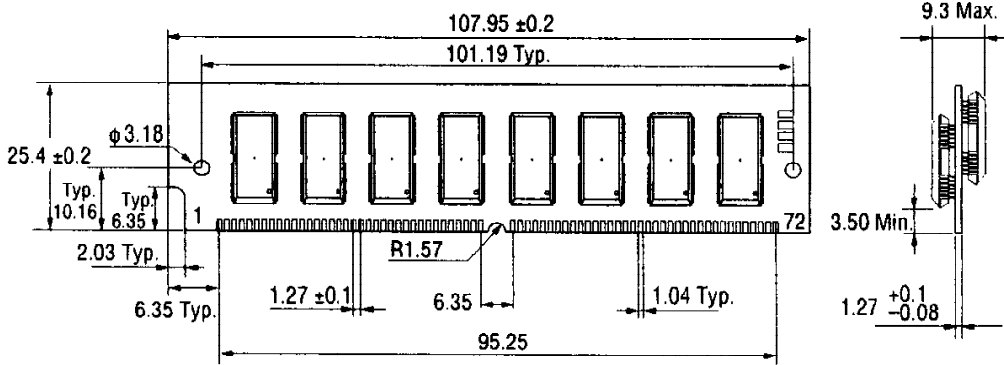
- 4-Meg × 36-bit organization
- 72-Pin Socket Insertable Module
 - MSC23436A-xxBS12 : Gold tab
 - MSC23436A-xxDS12 : Solder tab
- Single 5 V supply ±10% tolerance
- Access times : 60, 70, 80 ns
- Input : TTL compatible
- Output : TTL compatible, 3-state
- Refresh : 2048 cycles/32 ms
- CAS before RAS refresh, CAS before RAS hidden refresh, RAS-only refresh capability
- Fast Page Mode capability

PRODUCT FAMILY

Family	Access Time (Max.)			Cycle Time (Min.)	Power Dissipation	
	t _{RAC}	t _{AA}	t _{CAC}		Operating (Max.)	Standby (Max.)
MSC23436A-60BS12/DS12	60 ns	30 ns	15 ns	110 ns	7480 mW	66 mW (MOS level)
MSC23436A-70BS12/DS12	70 ns	35 ns	20 ns	130 ns	6820 mW	
MSC23436A-80BS12/DS12	80 ns	40 ns	20 ns	150 ns	6160 mW	

PIN CONFIGURATION

MSC23436A-xxBS12/DS12



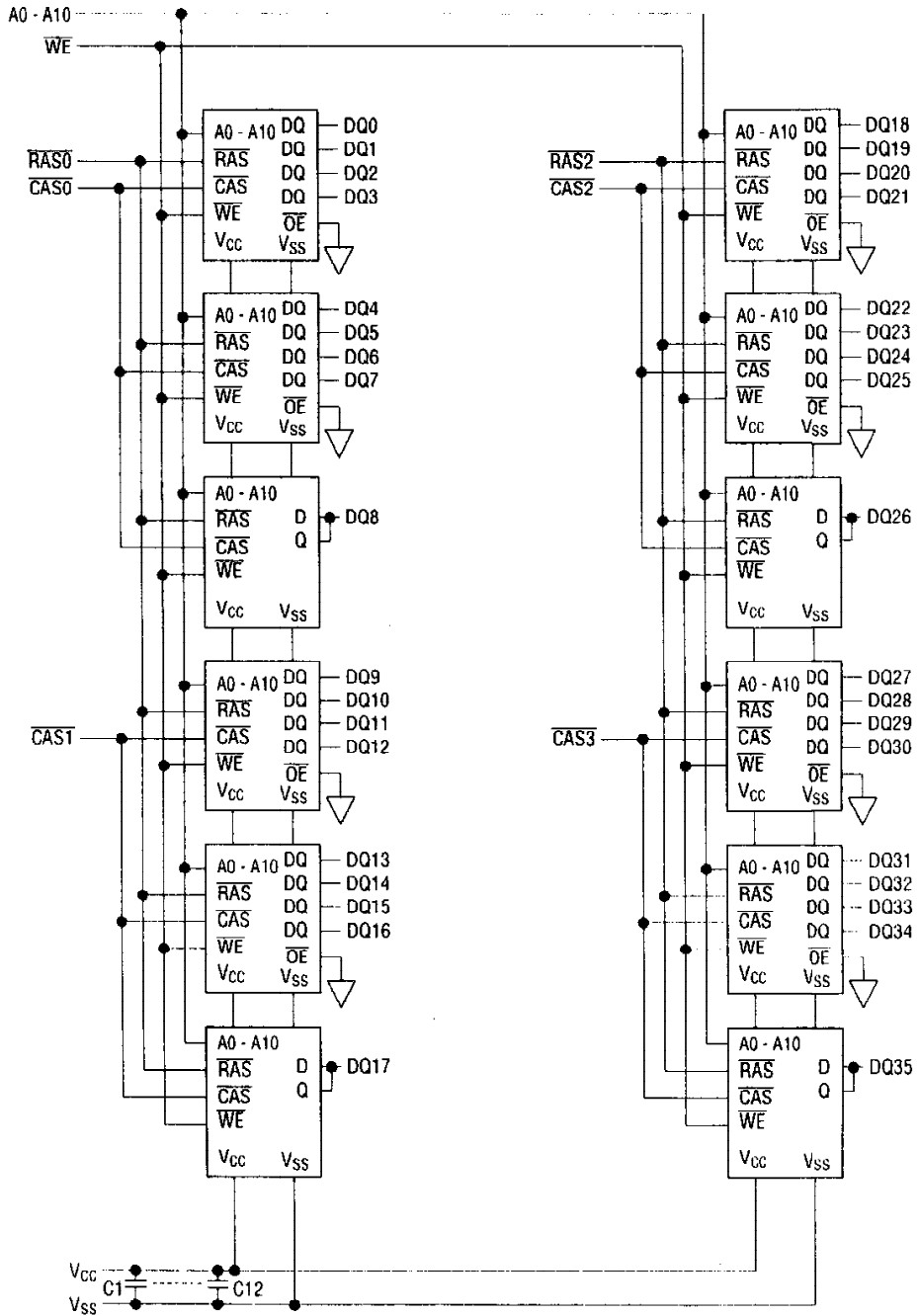
*1 The common size difference of the board width 12.5 mm of its height is specified as ±0.2. The value above 12.5 mm is specified as ±0.5.

Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name
1	V _{SS}	16	A4	31	A8	46	NC	61	DQ14
2	DQ0	17	A5	32	A9	47	\overline{WE}	62	DQ33
3	DQ18	18	A6	33	NC	48	NC	63	DQ15
4	DQ1	19	A10	34	$\overline{RAS2}$	49	DQ9	64	DQ34
5	DQ19	20	DQ4	35	DQ26	50	DQ27	65	DQ16
6	DQ2	21	DQ22	36	DQ8	51	DQ10	66	NC
7	DQ20	22	DQ5	37	DQ17	52	DQ28	67	PD1
8	DQ3	23	DQ23	38	DQ35	53	DQ11	68	PD2
9	DQ21	24	DQ6	39	V _{SS}	54	DQ29	69	PD3
10	V _{CC}	25	DQ24	40	$\overline{CAS0}$	55	DQ12	70	PD4
11	NC	26	DQ7	41	$\overline{CAS2}$	56	DQ30	71	NC
12	A0	27	DQ25	42	$\overline{CAS3}$	57	DQ13	72	V _{SS}
13	A1	28	A7	43	$\overline{CAS1}$	58	DQ31		
14	A2	29	NC	44	$\overline{RAS0}$	59	V _{CC}		
15	A3	30	V _{CC}	45	NC	60	DQ32		

Presence Detect Pins

Pin No.	Pin Name	MSC23436A -60BS12/DS12	MSC23436A -70BS12/DS12	MSC23436A -80BS12/DS12
67	PD1	V _{SS}	V _{SS}	V _{SS}
68	PD2	NC	NC	NC
69	PD3	NC	V _{SS}	NC
70	PD4	NC	NC	V _{SS}

BLOCK DIAGRAM



ELECTRICAL CHARACTERISTICS**Absolute Maximum Ratings**

Parameter	Symbol	Rating	Unit
Voltage on Any Pin Relative to V _{SS}	V _{IN} , V _{OUT}	-1.0 to 7.0	V
Voltage V _{CC} Supply Relative to V _{SS}	V _{CC}	-1.0 to 7.0	V
Short Circuit Output Current	I _{OS}	50	mA
Power Dissipation	P _D	12	W
Operating Temperature	T _{opr}	0 to 70	°C
Storage Temperature	T _{stg}	-40 to 125	°C

Note: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Recommended Operating Conditions(T_a = 0°C to 70°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit
Power Supply Voltage	V _{CC}	4.5	5.0	5.5	V
	V _{SS}	0	0	0	V
Input High Voltage	V _{IH}	2.4	—	6.5	V
Input Low Voltage	V _{IL}	-1.0	—	0.8	V

Capacitance(T_a = 25°C, f = 1 MHz)

Parameter	Symbol	Typ.	Max.	Unit
Input Capacitance (A0 - A10)	C _{IN1}	—	83	pF
Input Capacitance (\overline{WE})	C _{IN2}	—	95	pF
Input Capacitance ($\overline{RAS0}$, $\overline{RAS2}$)	C _{IN3}	—	50	pF
Input Capacitance ($\overline{CAS0}$ - $\overline{CAS3}$)	C _{IN4}	—	28	pF
I/O Capacitance (DQ0 - DQ7, DQ9 - DQ16, DQ18 - DQ25, DQ27 - DQ34)	C _{DQ1}	—	16	pF
I/O Capacitance (DQ8, DQ17, DQ26, DQ35)	C _{DQ2}	—	19	pF

Note : Capacitance measured with Boonton Meter.

DC Characteristics

 $(V_{CC} = 5 V \pm 10\%, T_a = 0^\circ C \text{ to } 70^\circ C)$

Parameter	Symbol	Condition	MSC23436A -60BS12/DS12		MSC23436A -70BS12/DS12		MSC23436A -80BS12/DS12		Unit	Note
			Min.	Max.	Min.	Max.	Min.	Max.		
Input Leakage Current	I_{LI}	$0 V \leq V_I \leq 6.5 V$; All other pins not under test = $0 V$	-120	120	-120	120	-120	120	μA	
Output Leakage Current	I_{LO}	DOUT disable $0 V \leq V_O \leq 5.5 V$	-10	10	-10	10	-10	10	μA	
Output High Voltage	V_{OH}	$I_{OH} = -5.0 \text{ mA}$	2.4	V_{CC}	2.4	V_{CC}	2.4	V_{CC}	V	
Output Low Voltage	V_{OL}	$I_{OL} = 4.2 \text{ mA}$	0	0.4	0	0.4	0	0.4	V	
Average Power Supply Current (Operating)	I_{CC1}	\overline{RAS} , \overline{CAS} cycling, $t_{RC} = \text{Min.}$	—	1360	—	1240	—	1120	mA	1, 2
Power Supply Current (Standby)	I_{CC2}	\overline{RAS} , $\overline{CAS} = V_{IH}$	—	24	—	24	—	24	mA	1
		\overline{RAS} , \overline{CAS} $\geq V_{CC} - 0.2 V$	—	12	—	12	—	12	mA	1
Average Power Supply Current (\overline{RAS} -only Refresh)	I_{CC3}	\overline{RAS} cycling, $\overline{CAS} = V_{IH}$, $t_{RC} = \text{Min.}$	—	1360	—	1240	—	1120	mA	1, 2
Average Power Supply Current (\overline{CAS} before \overline{RAS} Refresh)	I_{CC6}	\overline{RAS} cycling, \overline{CAS} before \overline{RAS} , $t_{RC} = \text{Min.}$	—	1360	—	1240	—	1120	mA	1, 2
Average Power Supply Current (Fast Page Mode)	I_{CC7}	$\overline{RAS} = V_{IL}$, \overline{CAS} cycling, $t_{PC} = \text{Min.}$	—	1200	—	1080	—	960	mA	1, 3

- Notes: 1. Specified values are obtained with the output open.
 2. Address can be changed once or less while $\overline{RAS} = V_{IL}$.
 3. Address can be changed once or less while $\overline{CAS} = V_{IH}$.

AC Characteristics (1/2)

(V_{CC} = 5 V ±10%, T_a = 0°C to 70°C) Note 1,2,3

Parameter	Symbol	MSC23436A -60BS12/DS12		MSC23436A -70BS12/DS12		MSC23436A -80BS12/DS12		Unit	Note
		Min.	Max.	Min.	Max.	Min.	Max.		
		Random Read or Write Cycle Time	t _{RC}	110	—	130	—		
Fast Page Mode Cycle Time	t _{PC}	40	—	45	—	50	—	ns	
Access Time from RAS	t _{RAC}	—	60	—	70	—	80	ns	4, 5, 6
Access Time from CAS	t _{CAC}	—	15	—	20	—	20	ns	4, 5
Access Time from Column Address	t _{AA}	—	30	—	35	—	40	ns	4, 6
Access Time from CAS Precharge	t _{CPA}	—	35	—	40	—	45	ns	4
Output Low Impedance Time from CAS	t _{CLZ}	0	—	0	—	0	—	ns	4
Output Buffer Turn-off Delay Time	t _{OFF}	0	15	0	20	0	20	ns	7
Transition Time	t _T	3	50	3	50	3	50	ns	3
Refresh Period	t _{REF}	—	32	—	32	—	32	ms	
RAS Precharge Time	t _{RP}	40	—	50	—	60	—	ns	
RAS Pulse Width	t _{RAS}	60	10K	70	10K	80	10K	ns	
RAS Pulse Width (Fast Page Mode)	t _{RASP}	60	100K	70	100K	80	100K	ns	
RAS Hold Time	t _{RSH}	15	—	20	—	20	—	ns	
CAS Precharge Time	t _{CP}	10	—	10	—	10	—	ns	
CAS Pulse Width	t _{CAS}	15	10K	20	10K	20	10K	ns	
CAS Hold Time	t _{CSH}	60	—	70	—	80	—	ns	
CAS to RAS Precharge Time	t _{CRP}	10	—	10	—	10	—	ns	
RAS to CAS Delay Time	t _{RCD}	20	45	20	50	20	60	ns	5
RAS to Column Address Delay Time	t _{RAD}	15	30	15	35	15	40	ns	6
Row Address Set-up Time	t _{ASR}	0	—	0	—	0	—	ns	
Row Address Hold Time	t _{RAH}	10	—	10	—	15	—	ns	
Column Address Set-up Time	t _{ASC}	0	—	0	—	0	—	ns	
Column Address Hold Time	t _{CAH}	15	—	15	—	15	—	ns	
Column Address Hold Time from RAS	t _{AR}	50	—	55	—	60	—	ns	
Column Address to RAS Lead Time	t _{RAL}	30	—	35	—	40	—	ns	

AC Characteristics (2/2)

(V_{CC} = 5 V ±10%, T_a = 0°C to 70°C) Note 1,2,3

Parameter	Symbol	MSC23436A -60BS12/DS12		MSC23436A -70BS12/DS12		MSC23436A -80BS12/DS12		Unit	Note
		Min.	Max.	Min.	Max.	Min.	Max.		
		Read Command Set-up Time	t _{RCS}	0	—	0	—		
Read Command Hold Time	t _{RCH}	0	—	0	—	0	—	ns	8
Read Command Hold Time referenced to $\overline{\text{RAS}}$	t _{RRH}	0	—	0	—	0	—	ns	8
Write Command Set-up Time	t _{WCS}	0	—	0	—	0	—	ns	
Write Command Hold Time	t _{WCH}	10	—	15	—	15	—	ns	
Write Command Hold Time from $\overline{\text{RAS}}$	t _{WCR}	45	—	55	—	60	—	ns	
Write Command Pulse Width	t _{WP}	10	—	10	—	10	—	ns	
Write Command to $\overline{\text{RAS}}$ Lead Time	t _{RWL}	15	—	20	—	20	—	ns	
Write Command to $\overline{\text{CAS}}$ Lead Time	t _{CWL}	15	—	20	—	20	—	ns	
Data-in Set-up Time	t _{DS}	0	—	0	—	0	—	ns	
Data-in Hold Time	t _{DH}	15	—	15	—	15	—	ns	
Data-in Hold Time from $\overline{\text{RAS}}$	t _{DHR}	50	—	55	—	60	—	ns	
$\overline{\text{CAS}}$ Active Delay Time from $\overline{\text{RAS}}$ Precharge	t _{RPC}	10	—	10	—	10	—	ns	
$\overline{\text{RAS}}$ to $\overline{\text{CAS}}$ Set-up Time ($\overline{\text{CAS}}$ before $\overline{\text{RAS}}$)	t _{CSR}	10	—	10	—	10	—	ns	
$\overline{\text{RAS}}$ to $\overline{\text{CAS}}$ Hold Time ($\overline{\text{CAS}}$ before $\overline{\text{RAS}}$)	t _{CHR}	20	—	20	—	20	—	ns	
$\overline{\text{CAS}}$ Precharge Time (Refresh Counter Test)	t _{CPT}	40	—	40	—	40	—	ns	
$\overline{\text{WE}}$ to $\overline{\text{RAS}}$ Precharge Time ($\overline{\text{CAS}}$ before $\overline{\text{RAS}}$)	t _{WTS}	10	—	10	—	10	—	ns	
$\overline{\text{WE}}$ Hold Time from $\overline{\text{RAS}}$ ($\overline{\text{CAS}}$ before $\overline{\text{RAS}}$)	t _{WTH}	10	—	10	—	10	—	ns	

- Notes:
1. A start-up delay of 200 μ s is required after power-up followed by a minimum of eight initialization cycles ($\overline{\text{RAS}}$ -only refresh or $\overline{\text{CAS}}$ before $\overline{\text{RAS}}$ refresh) before proper device operation is achieved.
When using the internal refresh counter, a minimum of eight $\overline{\text{CAS}}$ before $\overline{\text{RAS}}$ initialization cycles is required.
 2. AC measurement assume $t_T = 5$ ns.
 3. V_{IH} (Min.) and V_{IL} (Max.) are reference levels for measuring input timing signals. Transition times are measured between V_{IH} and V_{IL} .
 4. Measured with a load circuit equivalent to 2 TTL loads and 100 pF.
 5. Operation within the t_{RCD} (Max.) limit ensures that t_{RAC} (Max.) can be met. t_{RCD} (Max.) is specified as a reference point only. If t_{RCD} is greater than the specified t_{RCD} (Max.) limit, access time is controlled by t_{CAC} .
 6. Operation within the t_{RAD} (Max.) limit ensures that t_{RAC} (Max.) can be met. t_{RAD} (Max.) is specified as a reference point only. If t_{RAD} is greater than the specified t_{RAD} (Max.) limit, access time is controlled by t_{AA} .
 7. t_{OFF} (Max.) defines the time at which the output achieves an open circuit condition and is not referenced to output voltage levels.
 8. t_{RCH} or t_{RRH} must be satisfied for a read cycle.

See ADDENDUM D for AC Timing Waveforms